



LM8272 Dual RRIO, High Output Current & Unlimited Cap Load Op Amp in Miniature Package

1 Features

($V_S = 12V$, $T_A = 25^\circ C$, Typical values unless specified).

- GBWP 15MHz
- Wide supply voltage range 2.5 V to 24 V
- Slew rate 15 V/ μs
- Supply current/channel 0.95 mA
- Cap load tolerance Unlimited
- Output short circuit current ± 130 mA
- Output current (1 V from rails) ± 65 mA
- Input common mode voltage 0.3 V beyond rails
- Input voltage noise 15 nV/ $\sqrt{Hz}$
- Input current noise 1.4 pA/ $\sqrt{Hz}$

2 Applications

- TFT-LCD flat panel V_{COM} driver
- A/D converter buffer
- High side/low side sensing
- Headphone amplifier

3 Description

The LM8272 is a Rail-to-Rail input and output Op Amp which can operate with a wide supply voltage range. This device has high output current drive, greater than Rail-to-Rail input common mode voltage range, and unlimited capacitive load drive capability, while requiring only 0.95mA/channel supply current. It is specifically designed to handle the requirements of flat panel TFT panel V_{COM} driver applications as well as being suitable for other low power and medium speed applications which require ease of use and enhanced performance over existing devices.

Greater than Rail-to-Rail input common mode voltage range with 50 dB of Common Mode Rejection allows high side and low side sensing among many applications without concerns for exceeding the range and with no compromise in accuracy. An exceptionally wide operating supply voltage range of 2.5 V to 24 V removes any concerns over functionality under extreme conditions and offers flexibility of use in multitude of applications. In addition, most device parameters are insensitive to power supply variations. This design enhancement is yet another step in simplifying its usage.

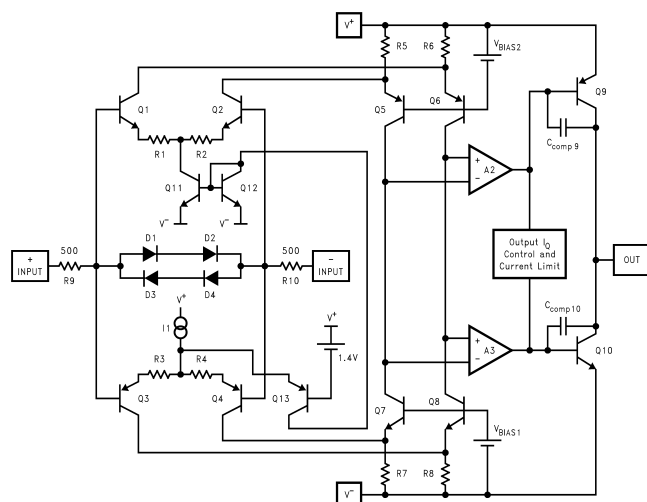
The LM8272 is offered in the 8-pin VSSOP package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM8272	VSSOP (8)	3.00 mm $\times$ 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic



**Large Signal Step Response
for Various Cap. Load**

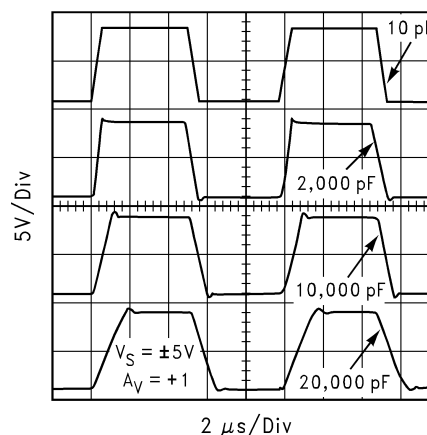


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7.1 Block Diagram and Operational Description A) Input			

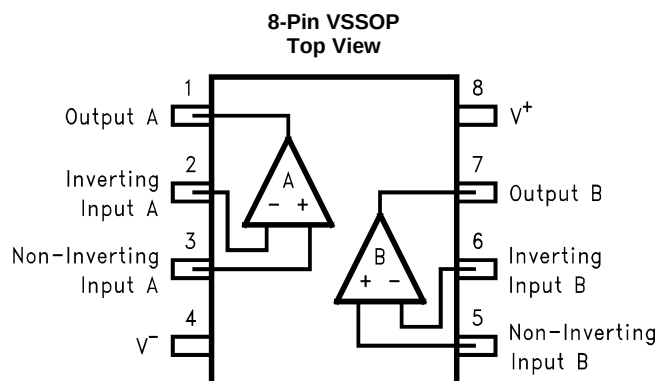
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (March 2013) to Revision E	Page
• Changed data sheet structure and organization. Added, updated, or renamed the following sections: Device Information Table, Application and Implementation; Power Supply Recommendations; Mechanical, Packaging, and Ordering Information.	1
• Deleted T _j = 25°C.....	5
• Deleted T _j = 25°C	6

Changes from Revision C (March 2013) to Revision D	Page
• Changed layout of National Data Sheet to TI format	18

5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NUMBER	NAME		
1	OUT A	O	Output A
2	-IN A	I	Inverting Input A
3	+IN A	I	Non-Inverting Input A
4	V-	I	Negative Supply
5	-IN B	I	Inverting Input B
6	+IN B	I	Non-Inverting Input B
7	OUT B	O	Output B
8	V+	I	Positive Supply

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
V _{IN} Differential		+/-10	V
Output Short Circuit Duration		See ⁽³⁾⁽⁴⁾	
Supply Voltage (V ⁺ - V ⁻)		27	V
Voltage at Input/Output pins		V ⁺ +0.3, V ⁻ -0.3	V
Junction Temperature ⁽⁵⁾		+150	°C
Soldering Information:	Infrared or Convection (20 sec.)	235	°C
	Wave Soldering (10 sec.)	260	°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Rating indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.
- (4) Output short circuit duration is infinite for VS ≤ 6 V at room temperature and below. For VS > 6 V, allowable short circuit duration is 1.5 ms.
- (5) The maximum power dissipation is a function of TJ(max), R_{θJA}, and TA. The maximum allowable power dissipation at any ambient temperature is PD = (TJ(max) - TA)/ R_{θJA}. All numbers apply for packages soldered directly onto a PC board.

6.2 Handling Ratings

	MIN	MAX	UNIT
T _{stg} Storage temperature range	-65	+150	°C
V _(ESD) Electrostatic discharge ⁽¹⁾	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽²⁾	2000	V
	Machine Model (MM) ⁽³⁾	200	

- (1) Human body model, 1.5 kΩ in series with 100 pF. Machine Model, 0 Ω is series with 200 pF.
- (2) JEDEC document JEP155 states that 2000-V HBM allows safe manufacturing with a standard ESD control process.
- (3) JEDEC document JEP157 states that 200-V MM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply Voltage (V ⁺ - V ⁻)	2.5		24	V
Operating Temperature Range ⁽¹⁾	-40		+85	°C

- (1) The maximum power dissipation is a function of TJ(max), R_{θJA}, and TA. The maximum allowable power dissipation at any ambient temperature is PD = (TJ(max) - TA)/ R_{θJA}. All numbers apply for packages soldered directly onto a PC board.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾	DGK	UNIT
	8 Pins	
R _{θJA} Junction-to-ambient thermal resistance ⁽²⁾	235	°C/W

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).
- (2) The maximum power dissipation is a function of TJ(max), R_{θJA}, and TA. The maximum allowable power dissipation at any ambient temperature is PD = (TJ(max) - TA)/ R_{θJA}. All numbers apply for packages soldered directly onto a PC board.

6.5 5V Electrical Characteristics

Unless otherwise specified, all limited ensured for $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 0.5V$, $V_O = V^+/2$, and $R_L > 1M\Omega$ to V^- . **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LIMIT ⁽²⁾	UNIT
V_{OS}	Input Offset Voltage	$V_{CM} = 0.5V$ & $V_{CM} = 4.5V$	+/-0.7	+/-5 +/- 7	mV max
TC V_{OS}	Input Offset Average Drift	$V_{CM} = 0.5V$ & $V_{CM} = 4.5V$ ⁽³⁾	+/-2	—	$\mu V/^{\circ}C$
I_B	Input Bias Current	See ⁽⁴⁾	—	± 2.00 ± 2.70	μA max
I_{OS}	Input Offset Current		20	250 400	nA max
CMRR	Common Mode Rejection Ratio	V_{CM} stepped from 0V to 5V	80	64 61	dB min
+PSRR	Positive Power Supply Rejection Ratio	V^+ from 4.5V to 13V	100	78 74	dB min
CMVR	Input Common-Mode Voltage Range	CMRR > 50dB	-0.3	-0.1 0.0	V max
			5.3	5.1 5.0	V min
A_{VOL}	Large Signal Voltage Gain	$V_O = 0.5$ to $4.5V$, $R_L = 10k\Omega$ to $V^+/2$	80	64 60	dB min
V_O	Output Swing High	$R_L = 10k\Omega$ to V^-	4.93	4.85	V min
		$I_{SOURCE} = 5mA$	4.85	4.70	
	Output Swing Low	$R_L = 10k\Omega$ to V^+	215	250	mV max
		$I_{SINK} = 5mA$	300	350	
I_{SC}	Output Short Circuit Current	Sourcing to V^- $V_{ID} = 200mV$ ⁽⁵⁾	100	—	mA
		Sinking to V^+ $V_{ID} = -200mV$ ⁽⁵⁾	100	—	
I_{OUT}	Output Current	$V_{ID} = \pm 200mV$, $V_O = 1V$ from rails	± 55	—	mA
I_S	Supply Current (Both Channel)	No load, $V_{CM} = 0.5V$	1.8	2.3 2.8	mA max
SR	Slew Rate ⁽⁶⁾	$A_V = +1$, $V_I = 5V_{PP}$	12	—	V/ μs
f_u	Unity Gain Frequency	$V_I = 10mV_p$, $R_L = 2k\Omega$ to $V^+/2$	7.5	—	MHz
GBWP	Gain-Bandwidth Product	$f = 50KHz$	13	—	MHz
Φ_{im}	Phase Margin	$V_I = 10mV_p$, $R_L = 2k\Omega$ to $V^+/2$	55	—	deg
e_n	Input-Referred Voltage Noise	$f = 2KHz$, $R_S = 50\Omega$	15	—	nV/ $\sqrt{Hz}$
i_n	Input-Referred Current Noise	$f = 2KHz$	1.4	—	pA/ $\sqrt{Hz}$
f_{max}	Full Power Bandwidth	$Z_L = (20pF 10k\Omega)$ to $V^+/2$	700	—	kHz

(1) Typical Values represent the most likely parametric norm.

(2) All limits are ensured by testing or statistical analysis.

(3) Offset voltage average drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.

(4) Positive current corresponds to current flowing into the device.

(5) Short circuit test is a momentary test. Output short circuit duration is infinite for $V_S \leq 6V$ at room temperature and below. For $V_S > 6V$, allowable short circuit duration is 1.5ms.

(6) Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

6.6 12V Electrical Characteristics

Unless otherwise specified, all limited ensured for $V^+ = 12V$, $V^- = 0V$, $V_{CM} = 6V$, $V_O = 6V$, and $R_L > 1M\Omega$ to V^- . **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LIMIT ⁽²⁾	UNIT
V_{OS}	Input Offset Voltage	$V_{CM} = 0.5V$ & $V_{CM} = 11.5V$	+/-0.7	+/-7 +/- 9	mV max
TC V_{OS}	Input Offset Average Drift	$V_{CM} = 0.5V$ & $V_{CM} = 11.5V$ ⁽³⁾	+/-2	—	$\mu V/^{\circ}C$
I_B	Input Bias Current	See ⁽⁴⁾	—	± 2.00 ± 2.80	μA max
I_{OS}	Input Offset Current		30	275 550	nA max
CMRR	Common Mode Rejection Ratio	V_{CM} stepped from 0V to 12V	88	74 72	dB min
+PSRR	Positive Power Supply Rejection Ratio	V^+ from 4.5V to 13V, $V_{CM} = 0.5V$	100	78 74	dB min
-PSRR	Negative Power Supply Rejection Ratio		85	—	dB
CMVR	Input Common-Mode Voltage Range	CMRR > 50dB	-0.3	-0.1 0	V max
			12.3	12.1 12.0	V min
A_{VOL}	Large Signal Voltage Gain	$V_O = 1V$ to 11V $R_L = 10k\Omega$ to $V^+/2$	83	74 70	dB min
V_O	Output Swing High	$R_L = 10k\Omega$ to $V^+/2$	11.8	11.7	V min
		$I_{SOURCE} = 5mA$	11.6	11.5	
	Output Swing Low	$R_L = 10k\Omega$ to $V^+/2$	0.25	0.3	V max
		$I_{SINK} = 5mA$	.40	.45	
I_{SC}	Output Short Circuit Current	Sourcing to V^- $V_{ID} = 200mV$ ⁽⁵⁾	130	110	mA min
		Sinking to V^+ $V_{ID} = 200mV$ ⁽⁵⁾	130	110	
I_{OUT}	Output Current	$V_{ID} = \pm 200mV$, $V_O = 1V$ from rails	± 65	—	mA
I_S	Supply Current (Both Channel)	No load, $V_{CM} = 0.5V$	1.9	2.4 2.9	mA max
SR	Slew Rate ⁽⁶⁾	$A_V = +1$, $V_I = 10V_{PP}$, $C_L = 10pF$	15	—	V/ μs
		$A_V = +1$, $V_I = 10V_{PP}$, $C_L = 0.1\mu F$	1	—	
R_{OUT}	Close Loop Output Resistance	$A_V = +1$, $f = 100KHz$	3	—	Ω
f_u	Unity Gain Frequency	$V_I = 10mV_p$, $R_L = 2k\Omega$ to $V^+/2$	8	—	MHz
GBWP	Gain-Bandwidth Product	$f = 50KHz$	15	—	MHz
Φ_{im}	Phase Margin	$V_I = 10mV_p$, $R_L = 2k\Omega$ to $V^+/2$	57	—	Deg
GM	Gain Margin	$V_I = 10mV_p$, $R_L = 2k\Omega$ to $V^+/2$	20	—	dB
-3dB BW	Small Signal -3db Bandwidth	$A_V = +1$, $R_L = 2k\Omega$ to $V^+/2$	12.5	—	MHz
		$A_V = +1$, $R_L = 600\Omega$ to $V^+/2$	10.5	—	
		$A_V = +10$, $R_L = 600\Omega$ to $V^+/2$	1.0	—	

(1) Typical Values represent the most likely parametric norm.

(2) All limits are ensured by testing or statistical analysis.

(3) Offset voltage average drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.

(4) Positive current corresponds to current flowing into the device.

(5) Short circuit test is a momentary test. Output short circuit duration is infinite for $V_S \leq 6V$ at room temperature and below. For $V_S > 6V$, allowable short circuit duration is 1.5ms.

(6) Slew rate is the slower of the rising and falling slew rates. Connected as a Voltage Follower.

12V Electrical Characteristics (continued)

Unless otherwise specified, all limited ensured for $V^+ = 12V$, $V^- = 0V$, $V_{CM} = 6V$, $V_O = 6V$, and $R_L > 1M\Omega$ to V^- . **Boldface** limits apply at the temperature extremes.

PARAMETER		TEST CONDITIONS	TYP ⁽¹⁾	LIMIT ⁽²⁾	UNIT
e_n	Input-Referred Voltage Noise	$f = 2KHz$, $R_S = 50\Omega$	15	—	$nV/\sqrt{Hz}$
i_n	Input-Referred Current Noise	$f = 2KHz$	1.4	—	$pA/\sqrt{Hz}$
f_{max}	Full Power Bandwidth	$Z_L = (20pF \parallel 10k\Omega)$ to $V^+/2$	300	—	kHz
THD+N	Total Harmonic Distortion +Noise	$A_V = +2$, $R_L = 2k\Omega$ to $V^+/2$ $V_O = 8V_{pp}$, $V_S = \pm 5V$	0.02%	—	
CT Rej.	Cross-Talk Rejection	$f = 5MHz$, Driver $R_L = 10k\Omega$ to $V^+/2$	68	—	dB

6.7 Typical Performance Characteristics

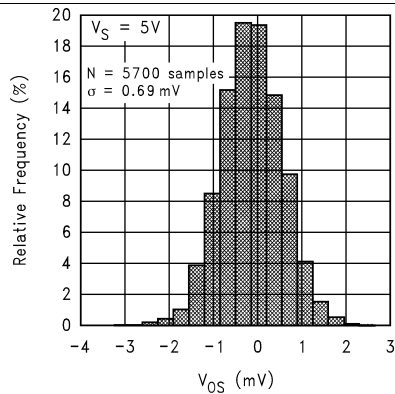


Figure 1. V_{OS} Distribution

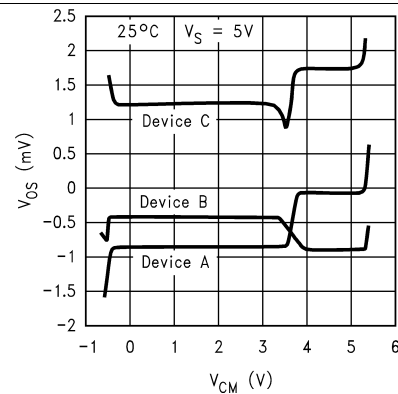


Figure 2. V_{OS} vs. V_{CM} for 3 Representative Units

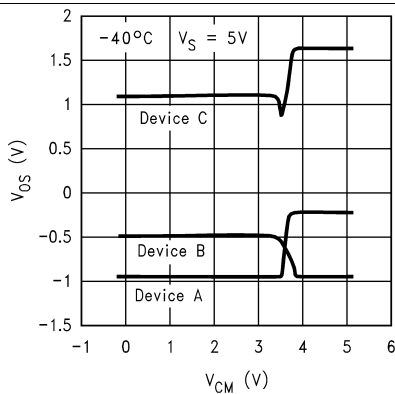


Figure 3. V_{OS} vs. V_{CM} for 3 Representative Units

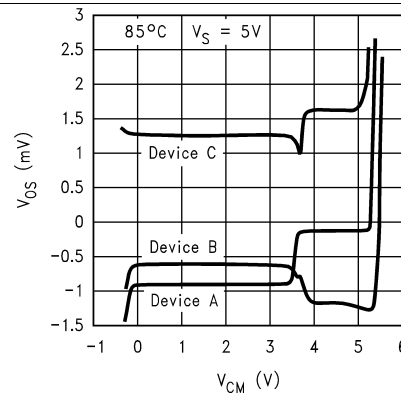


Figure 4. V_{OS} vs. V_{CM} for 3 Representative Units

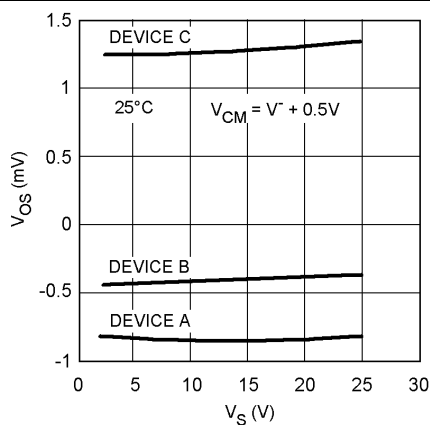


Figure 5. V_{OS} vs. V_S for 3 Representative Units

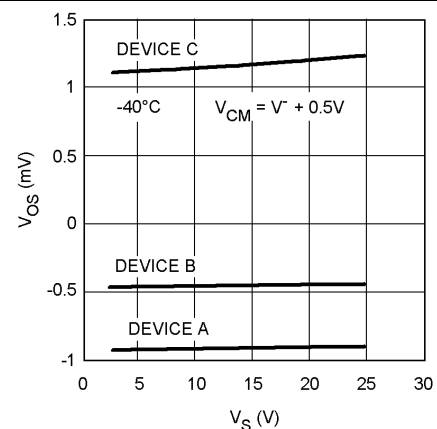


Figure 6. V_{OS} vs. V_S for 3 Representative Units

Typical Performance Characteristics (continued)

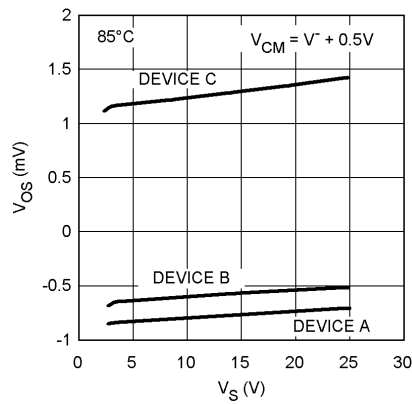


Figure 7. V_{OS} vs. V_S for 3 Representative Units

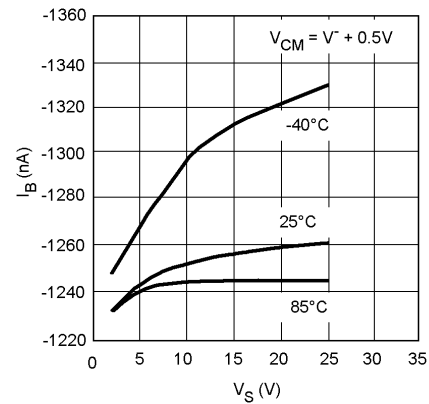


Figure 8. I_B vs. V_S

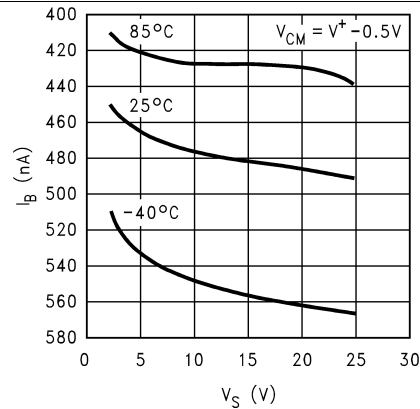


Figure 9. I_B vs. V_S

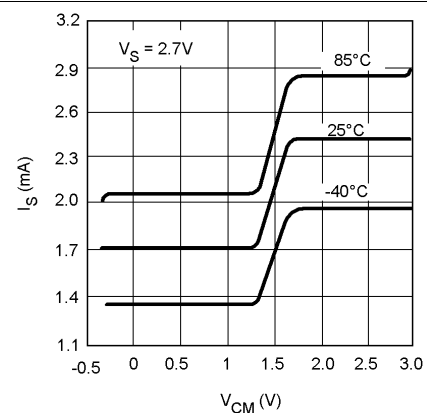


Figure 10. I_S vs. V_{CM}

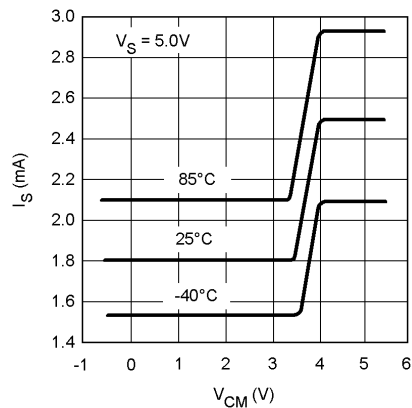


Figure 11. I_S vs. V_{CM}

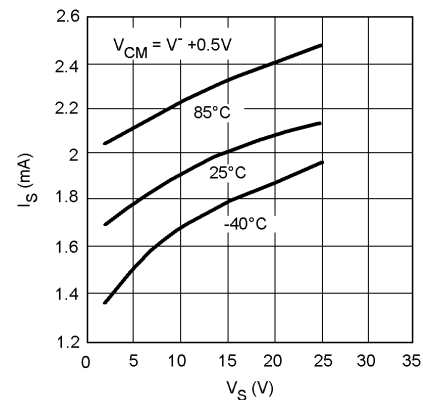
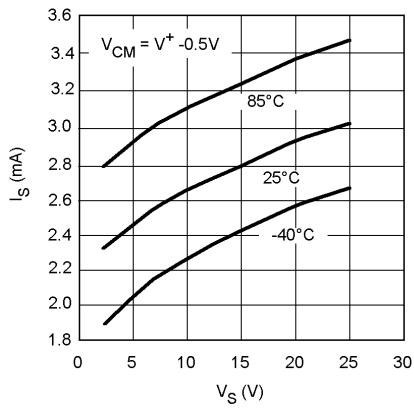
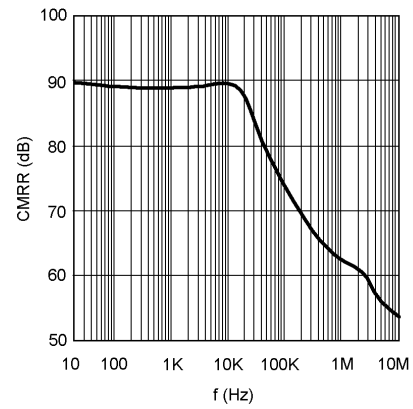
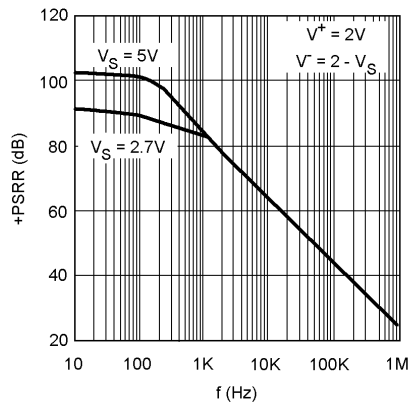
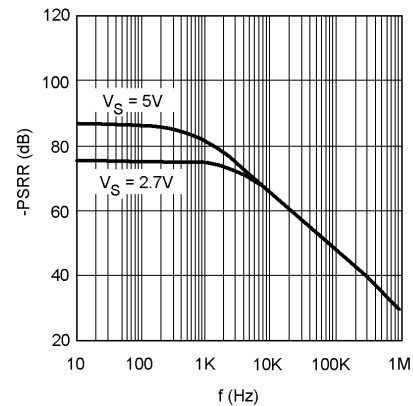
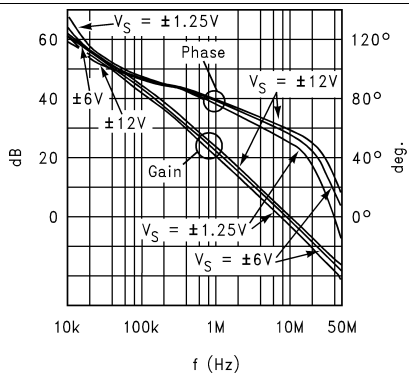
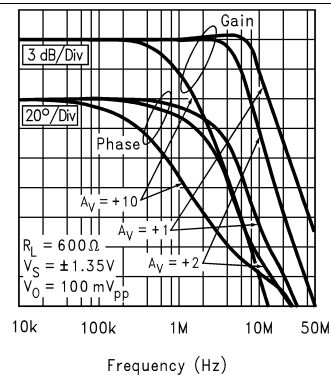


Figure 12. I_S vs. V_S

Typical Performance Characteristics (continued)

Figure 13. I_S vs. V_S

Figure 14. CMRR vs. Frequency

Figure 15. +PSRR vs. Frequency

Figure 16. -PSRR vs. Frequency

**Figure 17. Open Loop Gain/Phase
for Various Supplies**

**Figure 18. Closed Loop Frequency Response
for Various Gains**

Typical Performance Characteristics (continued)

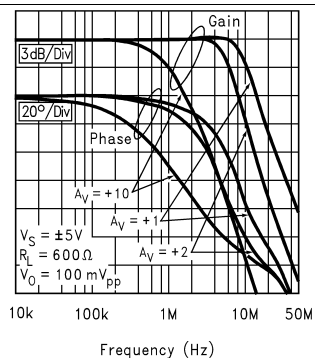


Figure 19. Closed Loop Frequency Response for Various Gains

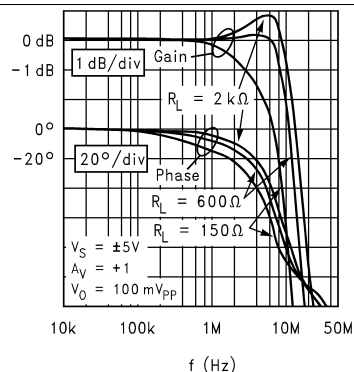


Figure 20. Closed Loop Frequency Response for Various R_L

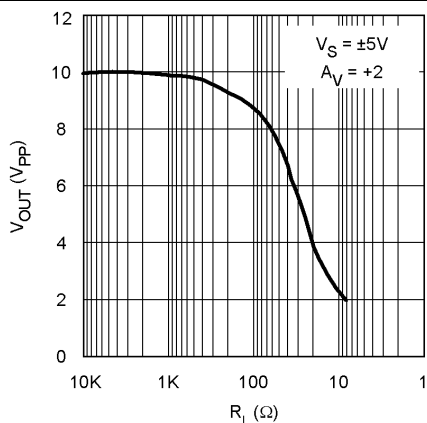


Figure 21. Maximum Output Swing vs. Load (1% Distortion)

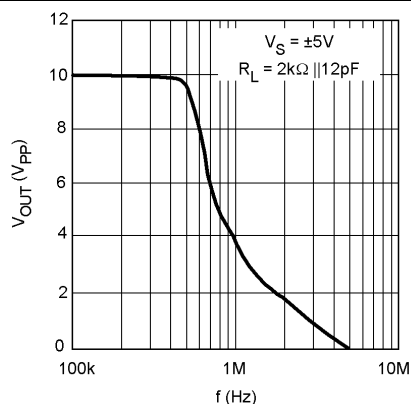


Figure 22. Maximum Output Swing vs. Frequency (1% Distortion)

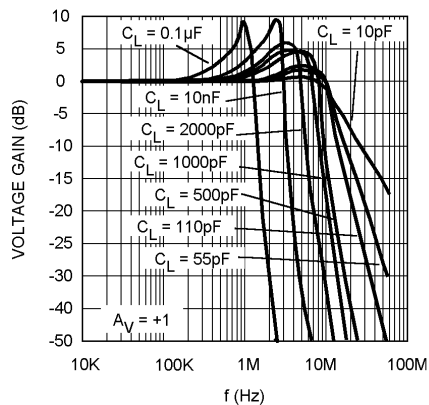


Figure 23. Closed Loop Small Signal Frequency Response for Various C_L

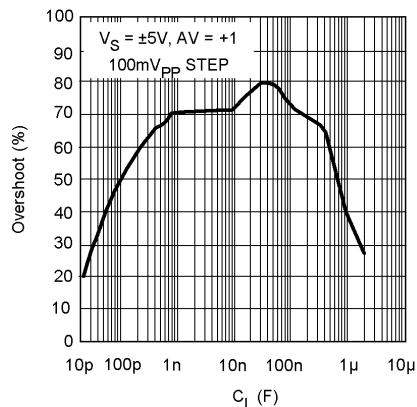
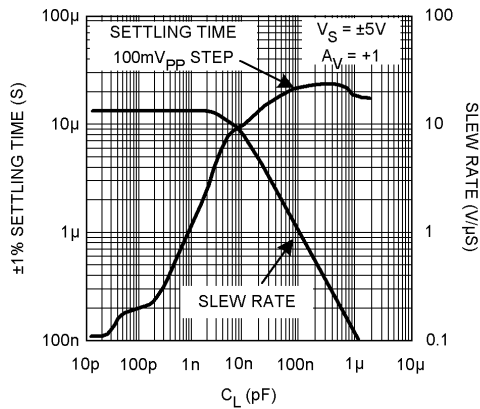
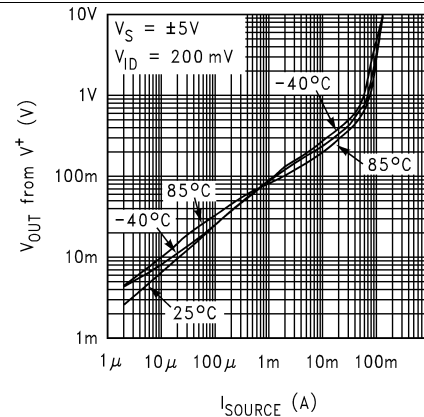
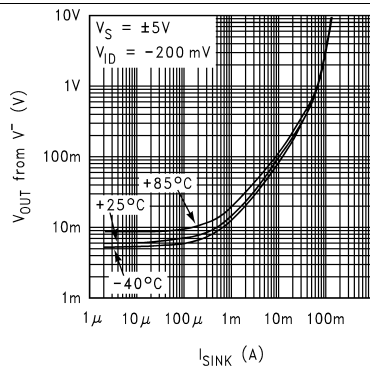
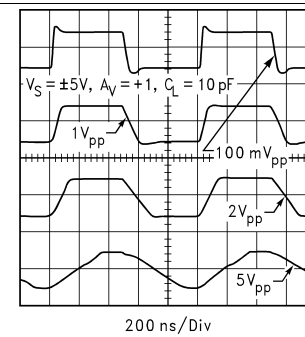
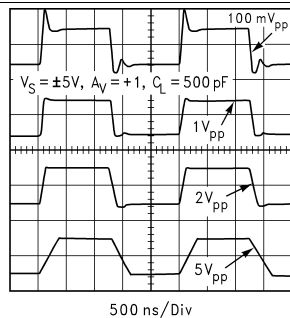
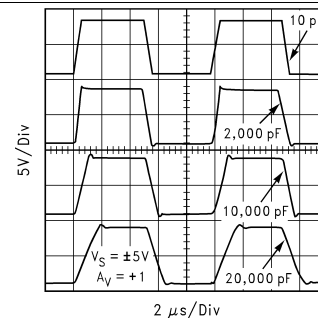


Figure 24. Overshoot vs. Cap Load

Typical Performance Characteristics (continued)

Figure 25. Settling Time (±1%) & Slew Rate vs. Cap Load

Figure 26. V_{OUT} from V^+ vs. I_{SOURCE}

Figure 27. V_{OUT} from V^- vs. I_{SINK}

Figure 28. Step Response for Various Amplitudes

Figure 29. Step Response for Various Amplitudes

Figure 30. Large Signal Step Response for Various Cap Loads

Typical Performance Characteristics (continued)

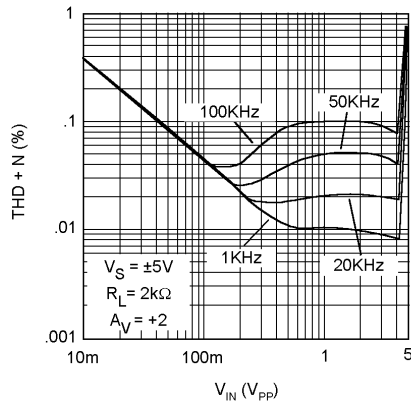


Figure 31. THD+N vs. Input Amplitude for Various Frequency

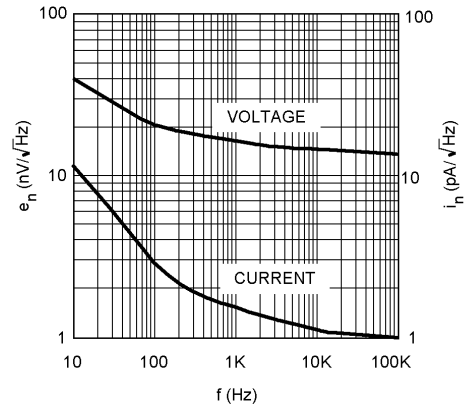


Figure 32. Input Referred Noise Density

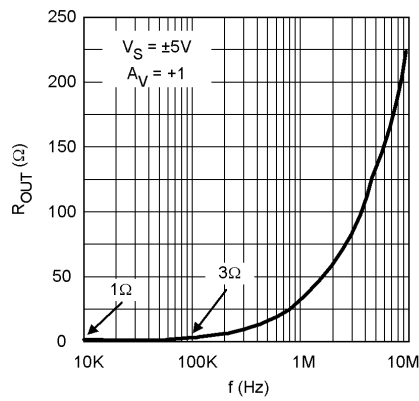


Figure 33. Closed Loop Output Impedance vs. Frequency

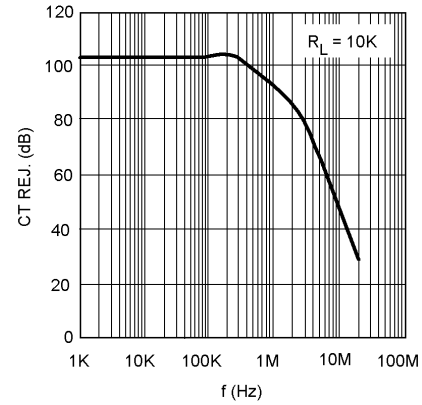


Figure 34. Crosstalk Rejection vs. Frequency

Block Diagram and Operational Description

A) Input Stage: (continued)

The input stage is protected with the combination of R9-R10 and D1, D2, D3 and D4 against differential input over-voltages. This fault condition could otherwise harm the differential pairs or cause offset voltage shift in case of prolonged over voltage. As shown in Figure 36, if this voltage reaches approximately $\pm 1.4\text{V}$ at 25°C , the diodes turn on and current flow is limited by the internal series resistors (R9 and R10). The Absolute Maximum Rating of $\pm 10\text{V}$ differential on V_{IN} still needs to be observed. With temperature variation, the point where the diodes turn on will change at the rate of $5\text{mV}/^\circ\text{C}$

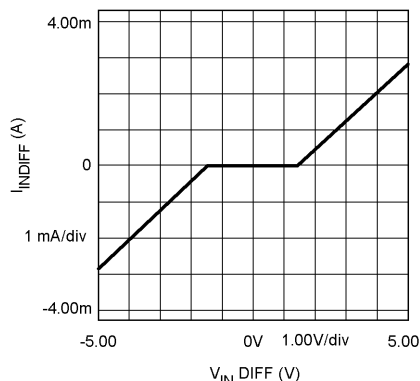


Figure 36. Input Stage Current vs. Differential Input Voltage

7.2 B) Output Stage:

The output stage (see Figure 35) is comprised of complimentary NPN and PNP common-emitter stages to permit voltage swing to within a $V_{\text{ce(sat)}}$ of either supply rail. Q9 supplies the sourcing and Q10 supplies the sinking current load. Output current limiting is achieved by limiting the V_{ce} of Q9 and Q10. Using this approach to current limiting alleviates the drawback to the conventional scheme which requires one V_{be} reduction in output swing.

The frequency compensation circuit includes Miller capacitors from collector to base of each output transistor (see Figure 35, C_{comp9} and C_{comp10}). At light capacitive loads, the high frequency gain of the output transistors is high, and the Miller effect increases the effective value of the capacitors thereby stabilizing the Op Amp. Large capacitive loads greatly decrease the high frequency gain of the output transistors thus lowering the effective internal Miller capacitance - the internal pole frequency increases at the same time a low frequency pole is created at the Op Amp output due to the large load capacitor. In this fashion, the internal dominant pole compensation, which works by reducing the loop gain to less than 0dB when the phase shift around the feedback loop is more than 180° , varies with the amount of capacitive load and becomes less dominant when the load capacitor has increased enough. Hence the Op Amp is very stable even at high values of load capacitance resulting in the uncharacteristic feature of stability under all capacitive loads.

7.3 C) Output Voltage Swing Close to V^- :

The LM8272's output stage design allows voltage swings to within millivolts of either supply rail for maximum flexibility and improved useful range. Because of this design architecture, as can be seen from Figure 35 diagram, with Output approaching either supply rail, either Q9 or Q10 Collector-Base junction reverse bias will decrease. With output less than a V_{be} from either rail, the corresponding output transistor operates near saturation. In this mode of operation, the transistor will exhibit higher junction capacitance and lower f_t which will reduce Phase Margin. With the Noise Gain ($\text{NG} = 1 + R_f/R_g$, R_f & R_g are external gain setting resistors) of 2 or higher, there is sufficient Phase Margin that this reduction (in Phase Margin) is of no consequence. However, with lower Noise Gain (< 2) and with less than 150mV voltage to the supply rail, if the output loading is light, the Phase Margin reduction could result in unwanted oscillations.

C) Output Voltage Swing Close to V^- : (continued)

In the case of the LM8272, due to inherent architectural specifics, the oscillation occurs only with respect to Q_{10} when output swings to within 150mV of V^- . However, if Q_{10} collector current is larger than its idle value of a few microamps, the Phase Margin loss becomes insignificant. In this case, 300 μ A is the required Q_{10} collector current to remedy this situation. Therefore, when all the aforementioned critical conditions are present at the same time ($NG < 2$, $V_{OUT} < 150$ mV from supply rails, & output load is light) it is possible to ensure stability by adding a load resistor to the output to provide the necessary Q_{10} minimum Collector Current (300 μ A).

For 12V (or ± 6 V) operation, for example, add a 39k Ω resistor from the output to V^+ to cause 300 μ A output sinking current and ensure stability. This is equivalent to about 15% increase in total quiescent power dissipation.

7.4 Driving Capacitive Loads:

The LM8272 is specifically designed to drive unlimited capacitive loads without oscillations (see [Figure 25](#)). In addition, the output current handling capability of the device allows for good slewing characteristics even with large capacitive loads (Settling Time and Slew Rate vs. Cap Load plot). The combination of these features is ideal for applications such as TFT flat panel buffers, A/D converter input amplifiers, etc.

However, as in most Op Amps, addition of a series isolation resistor between the Op Amp and the capacitive load improves the settling and overshoot performance.

Output current drive is an important parameter when driving capacitive loads. This parameter will determine how fast the output voltage can change. Referring to [Figure 25](#), two distinct regions can be identified. Below about 10,000pF, the output Slew Rate is solely determined by the Op Amp's compensation capacitor value and available current into that capacitor. Beyond 10nF, the Slew Rate is determined by the Op Amp's available output current. An estimate of positive and negative slew rates for loads larger than 100nF can be made by dividing the short circuit current value by the capacitor.

7.5 Estimating the Output Voltage Swing

It is important to keep in mind that the steady state output current will be less than the current available when there is an input overdrive present. For steady state conditions, [Figure 37](#) and [Figure 38](#) plots can be used to predict the output swing. These plots also show several load lines corresponding to loads tied between the output and ground. In each case, the intersection of the device plot at the appropriate temperature with the load line would be the typical output swing possible for that load. For example, a 600- Ω load can accommodate an output swing to within 100mV of V^- and to 250mV of V^+ ($V_S = \pm 5$ V) corresponding to a typical 9.65V_{PP} unclipped swing.

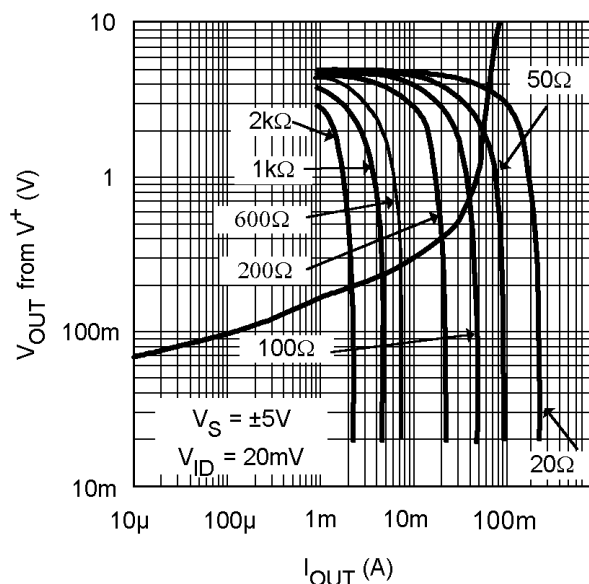


Figure 37. Steady State Output Sourcing Characteristics with Load Lines

Estimating the Output Voltage Swing (continued)

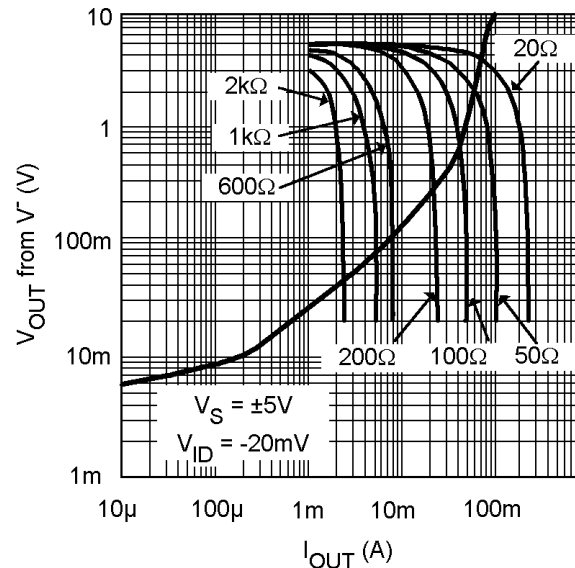


Figure 38. Steady State Output Sinking Characteristics with Load Lines

7.6 Output Short Circuit Current and Dissipation Issues:

The LM8272 output stage is designed for maximum output current capability. Even though momentary output shorts to ground and either supply can be tolerated at all operating voltages, longer lasting short conditions can cause the junction temperature to rise beyond the absolute maximum rating of the device, especially at higher supply voltage conditions. Below supply voltage of 6V, output short circuit condition can be tolerated indefinitely.

With the Op Amp tied to a load, the device power dissipation consists of the quiescent power due to the supply current flow into the device, in addition to power dissipation due to the load current. The load portion of the power itself could include an average value (due to a DC load current) and an AC component. DC load current would flow if there is an output voltage offset, or if the output AC average current is non-zero, or if the Op Amp operates in a single supply application where the output is maintained somewhere in the range of linear operation. Therefore:

$$P_{\text{total}} = P_Q + P_{\text{DC}} + P_{\text{AC}} \quad (1)$$

$$P_Q = I_S \cdot V_S \text{ (Op Amp Quiescent Power Dissipation)} \quad (2)$$

$$P_{\text{DC}} = I_O \cdot (V_r - V_O) \text{ (DC Load Power)} \quad (3)$$

P_{AC} = See Table 1 below (AC Load Power)

where:

- I_S : Supply Current
- V_S : Total Supply Voltage ($V^+ - V^-$)
- V_O : Average Output Voltage
- V_r : V^+ for sourcing and V^- for sinking current

Table 1 below shows the maximum AC component of the load power dissipated by the Op Amp for standard Sinusoidal, Triangular, and Square Waveforms:

Table 1. Normalized AC Power Dissipated in the Output Stage for Standard Waveforms

$P_{\text{AC}} \text{ (W.}\Omega/\text{V}^2\text{)}$		
SINUSOIDAL	TRIANGULAR	SQUARE
50.7×10^{-3}	46.9×10^{-3}	62.5×10^{-3}

The table entries are normalized to V_S^2/R_L . To figure out the AC load current component of power dissipation, simply multiply the table entry corresponding to the output waveform by the factor V_S^2/R_L . For example, with $\pm 12\text{V}$ supplies, a 600Ω load, and triangular waveform power dissipation in the output stage is calculated as:

$$P_{AC} = (46.9 \times 10^{-3}) \cdot [24^2/600] = 45.0\text{mW} \quad (4)$$

7.7 Other Application Hints:

The use of supply decoupling is mandatory in most applications. As with most relatively high speed/high output current Op Amps, best results are achieved when each supply line is decoupled with two capacitors; a small value ceramic capacitor ($\sim 0.01\mu\text{F}$) placed very close to the supply lead in addition to a large value Tantalum or Aluminum ($> 4.7\mu\text{F}$). The large capacitor can be shared by more than one device if necessary. The small ceramic capacitor maintains low supply impedance at high frequencies while the large capacitor will act as the charge “bucket” for fast load current spikes at the Op Amp output. The combination of these capacitors will provide supply decoupling and will help keep the Op Amp oscillation free under any load.

7.8 LM8272 Advantages:

Compared to other Rail-to-Rail Input/Output devices, the LM8272 offers several advantages such as:

- Improved cross over distortion
- Nearly constant supply current throughout the output voltage swing range and close to either rail.
- Nearly constant Unity gain frequency (f_u) and Phase Margin (Φ_{im}) for all operating supplies and load conditions.
- No output phase reversal under input overload condition.

8 Device and Documentation Support

8.1 Trademarks

All trademarks are the property of their respective owners.

8.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

8.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

9.1 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM8272MM	NRND	VSSOP	DGK	8	1000	TBD	Call TI	Call TI	-40 to 85	A60	
LM8272MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A60	Samples
LM8272MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A60	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

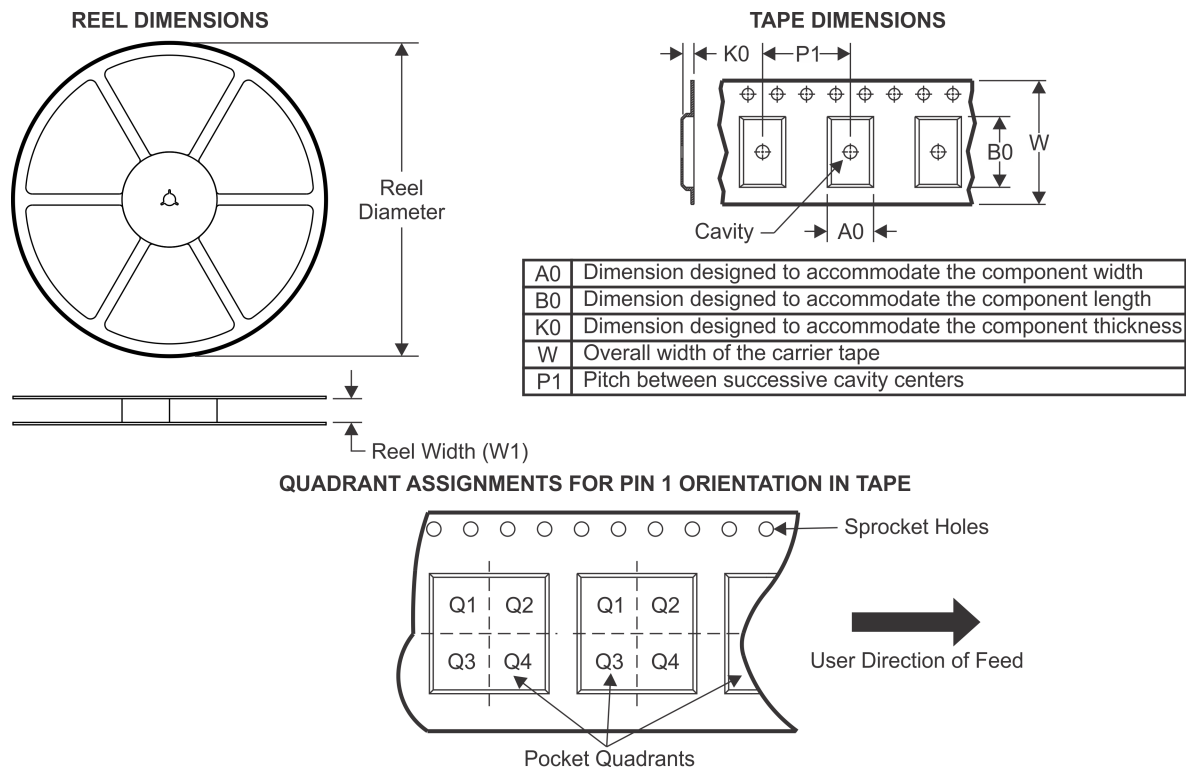
⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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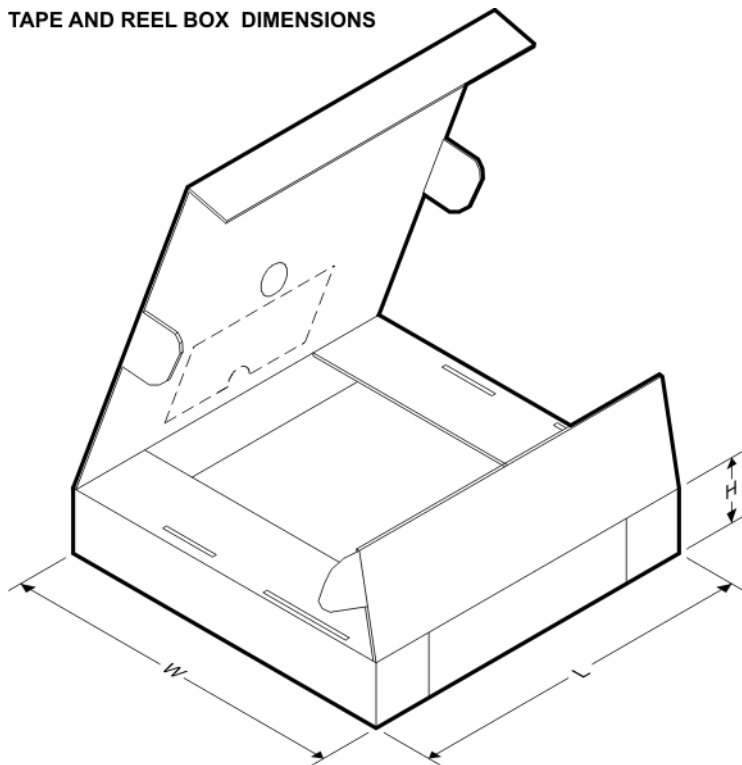
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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM8272MM	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM8272MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM8272MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

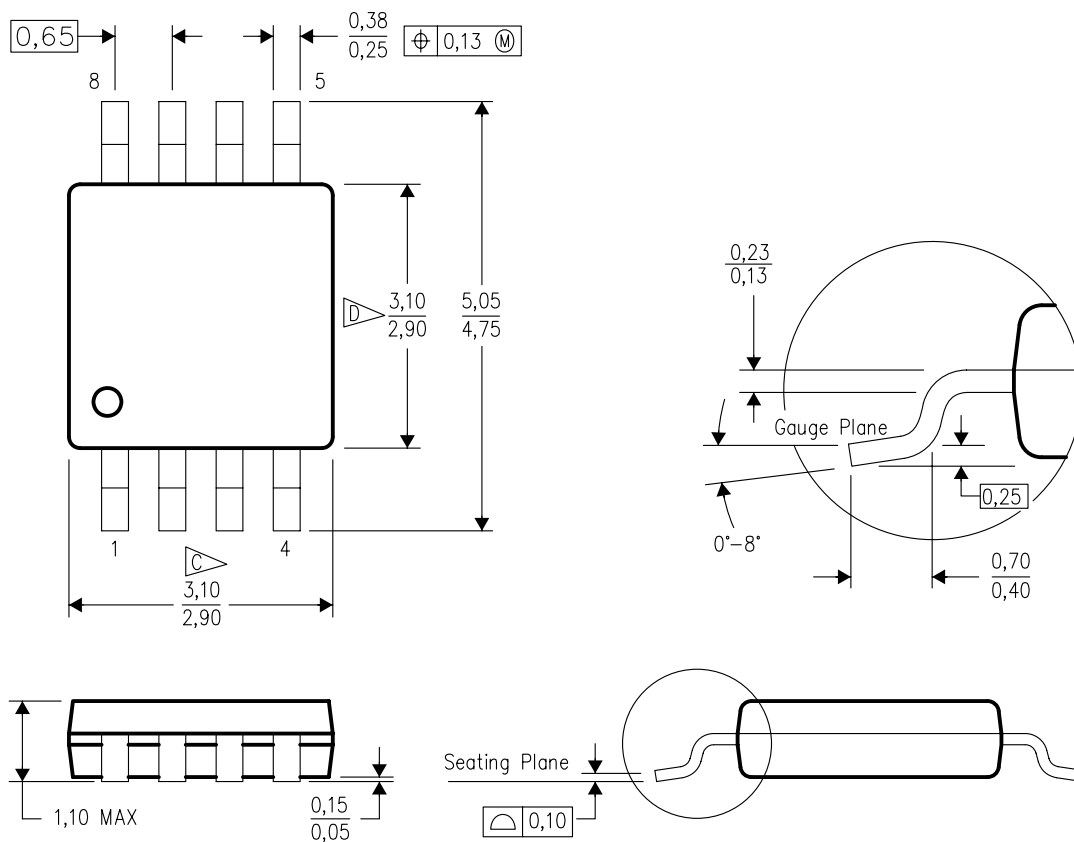


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM8272MM	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM8272MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM8272MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



4073329/E 05/06

NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- ☒ C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- ☐ D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

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